

Certificate

Standard **ISO 14001:2015**

Certificate Registr. No. 74 300 3516

Certificate Holder: **Micron Technology, Inc.**
8000 South Federal Way
Boise ID 83707-0006
USA

Scope: Design, Research and Development, Manufacture, Assembly and Test of Memory Components, Module and SSD Products

Proof has been furnished by means of an audit that the requirements of ISO 14001:2015 are met.

Validity: The certificate is valid from 2025-01-16 until 2028-01-15.
First certification 2013

2025-01-09



TUV Rheinland of North America, Inc.
400 Beaver Brook Road
Boxborough, MA 01719 United States

Annex to certificate

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No.	Location	Scope
/00	Micron Technology, Inc. Global EHS 8000 South Federal Way Boise ID 83707 USA	Central Function
/01	Micron Technology, Inc. 8000 South Federal Way Boise ID 83707-0006 USA	Design, Research and Development of Semiconductor Memory Components
/02	Micron Technology, Inc. 9600 Godwin Drive Manassas VA 20110 USA	Manufacturing and Testing of Semiconductor Wafers
/04	Micron Semiconductor Asia Operations Pte. Ltd. 990 Bendemeer Road Singapore 339942 Singapore	Manufacturing and Testing of Memory Component, Module and SSD products for Semiconductors
/05	Micron Semiconductor (Xi'an) Co., Ltd. No.28-2, Xin Xi Avenue, High-tech Industries Development Zone Xi'an, 710119 Shaanxi P.R. China	Manufacturing and Testing of Semiconductor Components and Module Products

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/06	Micron Semiconductor Malaysia Sdn. Bhd. Tanjung Agas Industrial Area No K1-5, PLO 107 (PTD 6571) 84007 Muar, Johor Malaysia	Manufacturing and Testing of Semiconductor Components
/07	Micron Semiconductor Asia Operations Pte. Ltd. 1 Woodlands Industrial Park D Singapore-Street 1 738799 Singapore	Manufacturing of Semiconductor Wafers
/08	Micron Semiconductor Asia Operations Pte. Ltd. 1 Northcoast Drive Singapore 757432 Singapore	Research and Development, Manufacturing and Testing of Semiconductor Wafers
/09	Micron Memory Taiwan Co., Ltd. No. 369, Sec 4, Sanfong Road Taichung City TWN 42152 Taiwan, R.O.C.	Manufacturing and Testing of Semiconductor Wafers
/11	Micron Memory Japan, K.K. 7-10 Yoshikawa Kogyo Danchi Higashi Hiroshima-shi Hiroshima, Hiroshima-ken 739-0198 Japan	Research and Development, Manufacturing and Testing of Semiconductor Wafers
/12	Micron Technology Taiwan, Inc. No.667, Fuxing 3rd Rd. Hwa-Ya Technology Park Taoyuan City 333 Taiwan, R.O.C.	Manufacturing of Semiconductor Wafers

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/13	Micron Memory Taiwan Co., Ltd. (MTB) No. 88 and 88-1, Houke S. Rd., Houli Dist., Taichung City 42152 Taiwan, R.O.C.	Manufacturing and Testing of Semiconductor Module Products
/15	Micron Memory Malaysia Sdn Bhd No. 1063, Plot 19 Tingkat Perusahaan 6 Prai Industrial Estate 13600 Prai, Penang Malaysia	Manufacturing and Testing of Semiconductor Module and SSD Products
/16	Micron Memory Malaysia Sdn. Bhd. Taman Perindustrian Batu Kawan Mukim 13, Seberang Perai Selatan PMT 779, Lingkaran Cassia Selatan Penang 14110 Bandar Cassia Malaysia	Manufacturing and Testing of Semiconductor Module, SSD Products and Component Assembly

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- /17 Micron Semiconductor Malaysia External Warehouse
Sdn. Bhd.
K93 (PLO 74), Jalan
Perindustrian 7
Tanjung Agas Industrial Area
External Warehouse (Golden
Sands II)
84007 Tangkak
Malaysia
- /18 Micron Memory Taiwan Co., Administration
Ltd.
No. 309, Sec. 2, Houke Rd.
Houli District
Taichung City 42152
Taiwan, R.O.C.
- /19 Micron Memory Japan, K.K. External Warehouse
Higashi Hiroshima-shi
3316-25,
Hachihonmatsuchōhara
Hiroshima
739-0151 Japan

2025-01-09



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